

## SCIENTIFIC PROGRAM

### ORAL SESSIONS

#### SECTION A

##### PROCESSING OF OXIDE FILMS AND MULTILAYERS

###### SESSION 1

THURSDAY, 28.09.2000, 9<sup>30</sup> - 12<sup>00</sup>

Chairman Dr. Albert FIGUERAS

- O1A. **Georg WAHL** (invited), *Institut für Oberflächentechnik und Plasmatechnische Werkstoffentwicklung, Technische Universität Braunschweig, Germany*  
INDUSTRIAL SCALE PROCESSING OF OXIDE LAYERS AND MULTILAYERS

- O2A. **Jean-Pierre SÉNATEUR** (invited), *LMGP, ENS de Physique de Grenoble, France*  
APPLICATION OF PULSED-INJECTION MOCVD TO THE SYNTHESIS OF MULTILAYERS AND SUPERLATTICES AT NANOMETRIC SCALE

- O3A. **Johannes LINDNER**, *AIXTRON AG, Aachen, Germany*  
INDUSTRIAL SCALE MOCVD PROCESSING OF ELECTROCERAMIC THIN FILMS

- O4A. **Catherine DUBOURDIEU**, *LMGP, ENS de Physique de Grenoble, France*  
PULSED LIQUID-INJECTION MOCVD OF MANGANITE - BASED SUPERLATTICES

- O5A. **Arunas TEISERSKIS**, *Vilnius University, Lithuania*  
LARGE AREA YBCO FILMS DEPOSITED BY PULSED INJECTION CVD

###### SESSION 2

THURSDAY, 28.09.2000, 14<sup>30</sup> - 16<sup>05</sup>

Chairman Dr. Francois WEISS

- O6A. **Andrej KAUL** (invited), *Moscow State University, Russia*  
EPITAXIAL PHASE STABILISATION PHENOMENA IN THIN FILM GROWTH

- O7A **Jose SANTISO**, *ICMAB-CSIC, Barcelona, Spain.*  
COMPOSITION DEPENDENCE OF THIN FILM GROWTH CHARACTERISTICS IN COMPLEX OXIDES.

- O8A. **Mazhar BARI**, *Trinity College, Dublin 2, Ireland*  
THIN FILMS OF Sr<sub>2</sub>FeMoO<sub>6</sub> DEPOSITED BY PULSED LASER DEPOSITION

- O9A **Ahti NIILISK**, *University of Tartu, Estonia*  
TIO<sub>2</sub> THIN FILMS BY ATOMIC\_LAYER CHEMICAL VAPOUR DEPOSITION: GROWTH AT 365 °C

**SECTION B**

**CHARACTERISATION AND APPLICATION OF OXIDE FILMS AND  
MULTILAYERS**

**SESSION 3**

FRIDAY, 29.09.2000, 9<sup>00</sup> – 10<sup>35</sup>

Chairman Prof. Michael COEY

O1B. **Josep FONTCUBERTA** (Invited), *Institut de Ciència de Materials de Barcelona, Spain*

Sr<sub>2</sub>FeMoO<sub>6</sub> DOUBLE PEROVSKITES. ARE THEY ALTERNATIVE MATERIALS FOR SPIN DEVICES?

O2B. **Oleg GORBENKO**, *Moscow State University, Russia*

NON-DESTRUCTIVE CHARACTERIZATION OF EPITAXIAL PEROVSKITE LAYERS BY RAMAN SPECTROSCOPY

O3B. **Bonifacas VENGALIS**, *Semiconductor Physics Institute, Vilnius, Lithuania*

SPIN-POLARIZED QUASIPARTICLE INJECTION DEVICE BASED ON MOCVD-GROVN YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub>/SrTiO<sub>3</sub>/La<sub>1-x</sub>Sr<sub>x</sub>MnO<sub>3</sub> HETEROSTRUCTURES

O4B. **Karol FRÖHLICH**, *Slovak Academy of Sciences, Bratislava, Slovak Republic*

NON-LINEAR CURRENT-VOLTAGE CHARACTERISTICS OF La<sub>1-x</sub>MnO<sub>3</sub> FILMS.

**SESSION 4**

FRIDAY, 29.09.2000, 10<sup>55</sup> – 12<sup>35</sup>

Chairman Dr. Karol FRÖHLICH

O5B. **Piotr DŁUŻEWSKI**, *Polish Academy of Scien, Warsaw, Poland*

TEM AND X-RAY CHARACTERIZATION OF MICROSTRUCTURE OF YBaCuO THIN FILMS DEPOSITED BY LASER ABLATION ON COLD SUBSTRATES

O6B. **A. GALDIKAS**, *Kaunas University of Technology, Lithuania*

ION BEAM DEPTH PROFILING OF MULTILAYERS

O7B. **Vladimir IGNATOVICH**, *FLNP JINR, Dubna, Moscow region, Russia*

MULTILAYERED SYSTEM WITH FORBIDDEN REFLECTIONS

O8B. **Sigitas TAMULEVICIUS**, *Kaunas University of Technology, Lithuania*

OPTICAL MEASUREMENTS OF STRAIN AND STRESS IN THIN FILMS

O9B. **Vladimir POKROPIVNY**, *Institute for Problems of Materials Science of NASU, Kiev, Ukraine*

NANOTUBULAR 2D CRYSTALS. SYNTHESIS AND PROMISING APPLICATIONS.

**POSTER SESSION**

THURSDAY, 28.09.2000, 16<sup>15</sup> - 18<sup>00</sup>

**SECTION A**

- P1A. **C. Jiménez<sup>a</sup>, F. Weiss<sup>a</sup>, J. P. Senateur<sup>a</sup>, A. Abrutis<sup>b</sup>, A. Teiserskis<sup>b</sup>, O. Stadel<sup>c</sup>, J. Schmidt<sup>c</sup>, G. Wahl<sup>c</sup>, M. Krellmann<sup>d</sup>, D. Selbmann<sup>d</sup>, N.V. Markov<sup>e</sup>, S. V. Samoylenkov<sup>e</sup>, O. Yu. Gorbenko<sup>e</sup>, A. R. Kaul<sup>e</sup>, F. Fillot<sup>f</sup>, H. Guillon<sup>f</sup>.**

<sup>a</sup> Laboratoire des Matériaux et du Génie Physique (LMGP), ENSPG, Rue de La Houille Blanche, Domaine Universitaire BP46, F-38402 Saint Martin D'Hères Cedex, France

<sup>b</sup> Vilnius University, Department of Chemistry, LT-2006 Vilnius, Lithuania

<sup>c</sup> Institut für Oberflächentechnik und Plasmatechnische Werkstoffentwicklung (IOPW), Technische Universität Braunschweig, Bienroder Weg 53, 38108 Braunschweig, Germany

<sup>d</sup> Institut für Festkörper und Werkstoffforschung Dresden (IFW), Postfach 270016, D-01171 Dresden, Germany

<sup>e</sup> Department of Chemistry, Moscow State University, 119899 Moscow, Russia.

<sup>f</sup> J.I.P.ELEC, 17 Chemin du Vieux Chêne, F-38240 Meylan, France

**DEPOSITION OF YBCO BY MOCVD FOR COATED CONDUCTORS FABRICATION**

- P2A. **L.Fàbrega<sup>1</sup>, M. Caussanel, R.Rubi<sup>1</sup>, J.Fontcuberta<sup>1</sup>, V.Trtík<sup>2</sup>, F.Sánchez<sup>2</sup>, C.Ferrater<sup>2</sup>, M. V. García-Cuenca<sup>2</sup> and M.Varela<sup>2</sup>**

<sup>1</sup>Institut de Ciència de Materials de Barcelona (C.S.I.C.), Campus de la U.A.B., 08193 Bellaterra, Spain, <sup>2</sup>Dpt. Física Aplicada i Óptica, Universitat de Barcelona, Diagonal 648, 08028 Barcelona, Spain

**FERROMAGNETIC AND SUPERCONDUCTING OXIDE HETEROSTRUCTURES FOR SPIN INJECTION DEVICES**

- P3A. **A.A.Bosak<sup>\*1</sup>, S.V.Samoilenkov<sup>1</sup>, O.Yu.Gorbenko<sup>1</sup>, A.N.Botev<sup>1</sup>, A.R.Kaul<sup>1</sup>, J.-P. Sénateur<sup>2</sup>, C.Dubourdieu<sup>2</sup>**

<sup>1</sup>Chemistry Department, MSU, 119899 Moscow, Russia, <sup>2</sup>ENSPG/LMGP, BP46, 38402, Saint Martin d'Hères, France

**SELF-TUNING APPROACH TO THE MOCVD OF HIGH-QUALITY LEAD-CONTAINING HETEROSTRUCTURES**

- P4A. **B. Vengalis, K. Oginskas, V. Lisauskas, R. Butkute, A. Maneikis, L. Dapkus, V. Jasutis and N. Shiktorov**

*Semiconductor Physics Institute, A.Goštauto 11, LT-2600 Vilnius, Lithuania,*  
**GROWTH AND INVESTIGATION OF THE (LaNiO<sub>3</sub>, RuO<sub>2</sub>)/La<sub>1-x</sub>Ca<sub>x</sub>MnO<sub>3</sub> HETEROSTRUCTURES**

- P5A. **V. Plausinaitienė<sup>1,2</sup>, A. Abrutis<sup>1</sup>, B. Vengalis<sup>2</sup>, R. Butkute<sup>2</sup>, J.P. Senateur<sup>3</sup>, Z. Saltyte<sup>1</sup>, V. Kubilius<sup>1</sup>, S.Pasko<sup>1</sup>, L.Dapkus<sup>2</sup>**

<sup>1</sup>Vilnius University, Dep. of General and Inorganic Chemistry, Naugarduko 24, LT-2006 Vilnius, Lithuania

<sup>2</sup>Semiconductor Physics Institute, A.Goštauto 11, LT-2600 Vilnius, Lithuania

<sup>3</sup>LMGP, ENSPG, INPG, UMR CNRS 5628, Saint Martin d'Hères, France

**MOCVD GROWTH AND CHARACTERISATION OF La<sub>1-x</sub>Sr<sub>x</sub>MnO<sub>3</sub>/SrTiO<sub>3</sub>/La<sub>1-x</sub>Sr<sub>x</sub>MnO<sub>3</sub> HETEROSTRUCTURES**

**P6A J. Santiso, V. Laukhin, G. Garcia and A. Figueras**

*Laboratorio de crecimiento cristalino, ICMAB-CSIC. Campus UAB. 08193 Bellaterra.  
Barcelona. Spain. E-mail santi@icmab.es*

**Ll. Balcells and J. Fontcuberta**

*Laboratorio de propiedades eléctricas y magnéticas, ICMAB-CSIC.*

**L.A. Angurel, R.I. Merino and V.M. Orera**

*ICMA-CSIC Zaragoza*

**OXIDE THIN FILM DEPOSITION ON EUTECTIC SUBSTRATES**

**P7A. P. B. Tavares**

*Secção de Química, Universidade de Trás-os-Montes e Alto Douro, 5000 Vila Real,  
Portugal, and Departamento de Engenharia Cerâmica e Vidro, Universidade de Aveiro,  
3810 Aveiro, Portugal*

**J. P. Araújo, J. B. Sousa**

*IFIMUP, Departamento de Física, Faculdade de Ciências da Universidade do Porto,  
Rua do Campo Alegre 687, 4150 Porto, Portugal.*

**V. S. Amaral**

*Departamento de Física, Universidade de Aveiro, 3810 Aveiro, Portugal.*

**J. M. Vieira**

*Departamento de Engenharia Cerâmica e Vidro, Universidade de Aveiro, 3810 Aveiro,  
Portugal*

**THE EFFECTS OF TEMPERATURE ON BISRCACUO THIN FILMS USING  
AEROSOL-ASSISTED METALORGANIC CHEMICAL VAPOR DEPOSITION  
(MOCVD).**

**P8A. A. Teiserskis, A. Abrutis, Z. Saltyte**

*Vilnius University, Dep. of General and Inorganic Chemistry, Naugarduko 24, LT-2006  
Vilnius, Lithuania*

**C. Jimenez, F. Weiss, J.P. Senateur**

*LMGP, ENSPG, INPG, UMR CNRS 5628, Saint Martin d'Hères, France*

**HongLi Suo, Jean-Yves Genoud, René Flükinger**

*D.P.M.C University of Geneva, CH-1211 Geneva 4, Switzerland*

**MOCVD DEPOSITION OF YBCO FILMS ON BIAXIALLY TEXTURED Ag  
SUBSTRATES**

**P9A. A. Rakauskas, J. Dudonis, V. Stankus**

*Kaunas University of Technology, studentų-50, LT-3000 Kaunas, Lithuania.*

**DEPOSITION OF OXIDE THIN FILMS BY THE COMBINED CATHODIC ARC-  
MAGNETRON SPUTTER TECHNIQUE**

**P10A. V. Stankus\*, A. Rakauskas, J. Dudonis**

*Kaunas University of Technology, studentų-50, LT-3000 Kaunas, Lithuania.*

**SYNTHESIS OF PbTiO<sub>3</sub> IN SPUTTERED Pb/Ti LAYER BY SOLID STATE  
REACTIONS**

**P11A. S. Rajesh, K. Perumal**

*Solar Energy Lab., Dept. of Physics, Sri Ramakrishna Mission Vidyalaya College of  
Arts and Science, Coimbatore-641020 India*

**EFFECT OF DEPOSITION PARAMETERS ON THE OPTOELECTRICAL  
PROPERTIES AND MICROSTRUCTURE OF THE SPIN COATED METAL OXIDE  
THIN FILMS**

## SECTION B

**P1B. M. Rosina<sup>a</sup>, K. Fröhlich<sup>a</sup>, C. Dubourdieu<sup>b</sup>, F. Weiss<sup>b</sup>, M. Jergel<sup>c</sup>**

<sup>a</sup>*Institute of Electrical Engineering, SAS, Dúbravská cesta 9, 842 39 Bratislava, Slovakia*

<sup>b</sup>*LMGP, UMR CNRS 5628, ENSPG BP 46, 38 402 Saint Martin d'Hères, France*

<sup>c</sup>*Institute of Physics, SAS, Dúbravská cesta 9, 842 28 Bratislava, Slovakia.*

**INVESTIGATION OF THE QUALITY OF SURFACES AND INTERFACES OF SINGLE LAYERS, BILAYERS AND MULTILAYERS BASED ON  $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$  BY AFM AND X-RAY REFLECTIVITY METHOD**

**P2B. M.Pripko<sup>a</sup>, K. Fröhlich<sup>a</sup>, M. Maryško<sup>b</sup>**

<sup>a</sup>*Institute of Electrical Engineering, Slovak Academy of Sciences, Dúbravská cesta 9, 842 39 Bratislava, Slovak Republic*

<sup>b</sup>*Institute of Physics, Czech Academy of Sciences, 162 53 Praha 6, Czech Republic*

**MAGNETO-TRANSPORT PROPERTIES OF OXYGEN POST-ANNEALED  $\text{LaMnO}_3$  THIN FILMS**

**P3B. A. Kalvane, M. Antonova, M. Livinsh, A. Spule, L. Shebanovs, A. Sternberg**

*Institute of Solid State Physics, University of Latvia, 8 Kengaraga str., Riga, LV 1063, Latvia*

**STRUCTURE AND PROPERTIES OF HIGH PIEZOELECTRIC COUPLING  $\text{Pb}(\text{B}', \text{B}'')\text{O}_3$  -  $\text{PbTiO}_3$  BINARY SYSTEMS**

**P4B. A.Jukna<sup>1</sup>, J.Paršeliūnas<sup>1</sup>, S.Balevičius<sup>1</sup>, O.Kiprijanovič<sup>1</sup>, V.Lisauskas<sup>1</sup>, A.Abrutis<sup>2</sup>, V.Plaušinaitienė<sup>2</sup>, A.Teišerskis<sup>2</sup>**

<sup>1</sup>*Semiconductor Physics Institute, A.Goštauto 11, LT-2600 Vilnius, Lithuania*

<sup>2</sup>*Vilnius University, Naugarduko 24, LT-2006 Vilnius, Lithuania*

**ELECTRIC PROPERTIES OF THIN SUPER-CONDUCTING FILM AERIAL**

**P5B. P. Dlużewski, A. Szczepańska, J. Pelka, W. Paszkowicz, A. Wawro, L.T. Baczewski**

*Institute of Physics, Polish Academy of Sciences, Al. Lotników 32/46, 02-668 Warsaw, Poland*

**X-RAY AND TEM STRUCTURAL STUDY OF Co/Gd MULTILAYERS WITH EXOTIC MAGNETIC PROPERTIES**

**P6B. G.-J.Babonas<sup>1</sup>, L.Leonyuk<sup>2</sup>, R.Szymczak<sup>3</sup>, A.Reza<sup>1</sup>, V.Maltsev<sup>2</sup>, M.Baran<sup>3</sup>, L.Dapkus<sup>1</sup>, V.Jasutis<sup>1</sup>**

<sup>1</sup>*Semiconductor Physics Institute, Goštauto 11, LT-2600 Vilnius, Lithuania*

<sup>2</sup>*Moscow State University, 119899 Moscow, Russia*

<sup>3</sup>*Institute of Physics, PAN, 02-668 Warsaw, Poland*

**SURFACE LAYERS ON  $(\text{M}_2\text{Cu}_2\text{O}_3)_m(\text{CuO}_2)_n$  SUPERCONDUCTORS**

**P7B. F. Anisimovas, J. Liberis, B. Vengalis**

*Semiconductor Physics Institute, Goštauto 11, LT-2600 Vilnius, Lithuania.*

**MICROWAVE NOISE IN  $\text{La}_{0.67}\text{Ca}_{0.33}\text{MnO}_3$  THIN FILMS**

P8B. **V. Karpus<sup>1</sup>, A. Rēza<sup>1</sup>, G.-J. Babonas<sup>1</sup>, A. Suchodolskis<sup>1</sup>, W. Assmus<sup>2</sup>, R. Sterzel<sup>2</sup>, V. Kazlauskienė<sup>3</sup>, J. Miškinis<sup>3</sup>, and A. Miniotas<sup>4</sup>**

<sup>1</sup> Semiconductor Physics Institute, Goštauto 11, LT-2600 Vilnius, Lithuania.

<sup>2</sup> J. W. Goethe-Universität, Postfach 111932, D-60054 Frankfurt am Main, Germany

<sup>3</sup> Vilnius University, Naugarduko 24, LT-2734 Vilnius, Lithuania

<sup>4</sup> Royal Institute of Technology, S-10044 Stockholm, Sweden

SURFACE OXIDE LAYERS ON *i*-ZnMg(Y,Ho) QUASICRYSTALS

P9B. **O.Kiprijanovič, S.Balevičius, V.Pyragas, E.E.Tornau, A.Jukna, B.Vengalis, F.Anisimovas**

*Semiconductor Physics Institute, Goštauto 11, LT-2600 Vilnius, Lithuania.*

EFFECT OF NANOSECOND MAGNETIC AND ELECTRIC PULSES ON RESISTANCE OF  $\text{La}_{0.67}\text{Ca}_{0.33}\text{MnO}_3$  THIN FILMS

P10B. **K. Bormanis, M. Kalnberga, M. Livinsh, A. Patmalnieks, and A. Sternberg**

*Institute of Solid State Physics, University of Latvia, 8 Kengaraga str., Riga, LV 1063, Latvia*

MICROSCOPIC STUDIES OF THE SURFACE OF FERROELECTRIC AND HIGH TEMPERATURE SUPERCONDUCTOR LAYERS

P11B. **V.Vaicikauskas, R.Antanavicius, R.Januskevicius, J.Bremer\*, O.Hunderi\***

*Institute of Physics, Goštauto 12, LT-2600 Vilnius, Lithuania*

\**Department of Physics, Norwegian University of Science and Technology, 7491 Trondheim, Norway*

OPTICAL CONSTANTS OF ITO DETERMINED BY ELLIPSOMETRY OF SURFACE PLASMONS

P12B. **A.Galdikas, S.Kačiulis, A.Mironas, D.Senulienė, V.Strazdienė and A.Šetkus**

*Semiconductor Physics Institute, Goštauto 11, Lt-2600 Vilnius, Lithuania*

SENSITIVITY TUNING BY ADDITIONAL LAYERS IN TiN OXIDE THIN FILM BASED GAS SENSORS

P13B. **I.E.Graboy<sup>\*1</sup>, O.Yu.Gorbenko<sup>1</sup>, M.A.Novojilov<sup>1</sup>, S.V.Samoylenkov<sup>1</sup>, A.R.Kaul<sup>1</sup>, H.W.Zandbergen<sup>2</sup>**

<sup>1</sup>*Department of Chemistry, Moscow State University, 119899 Moscow, Russia*

<sup>2</sup>*National Centre for HREM, Laboratory of Materials Science, Delft University of Technology, Rotterdamseweg 137, Delft 2628 AL, The Netherlands*

TRANSMISSION ELECTRON MICROSCOPY STUDY OF OXIDE HETEROSTRUCTURES